John S Preston

List of Publications by Year in descending order

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218677 118850 3,972 89 26 62 h-index citations g-index papers 89 89 89 3181 docs citations times ranked citing authors all docs

#	Article	IF	CITATIONS
1	Laser-induced periodic surface structure. I. Theory. Physical Review B, 1983, 27, 1141-1154.	3.2	1,153
2	Laser-induced periodic surface structure. II. Experiments on Ge, Si, Al, and brass. Physical Review B, 1983, 27, 1155-1172.	3.2	584
3	Microwave spectroscopy of thermally excited quasiparticles in YBa2Cu3O6.99. Physical Review B, 1999, 60, 1349-1359.	3.2	193
4	Disorder and superconducting-state conductivity of single crystals of YBa2Cu3O6.95. Physical Review B, 1994, 49, 12165-12169.	3.2	122
5	Laser drilling of high aspect ratio holes in copper with femtosecond, picosecond and nanosecond pulses. Applied Physics A: Materials Science and Processing, 2008, 90, 537-543.	2.3	119
6	In situgrowth of layered, spinel, and rockâ€salt LiCoO2by laser ablation deposition. Journal of Applied Physics, 1994, 76, 2799-2806.	2.5	103
7	Intrinsic picosecond response times of Y–Ba–Cu–O superconducting photodetectors. Applied Physics Letters, 1999, 74, 853-855.	3.3	98
8	Laserâ€induced periodic surface damage and radiation remnants. Applied Physics Letters, 1982, 41, 261-264.	3.3	88
9	Observation of Weak-Limit Quasiparticle Scattering via Broadband Microwave Spectroscopy of ad-Wave Superconductor. Physical Review Letters, 2003, 90, 237005.	7.8	67
10	Vertically aligned wurtzite CdTe nanowires derived from a catalytically driven growth mode. Nanotechnology, 2007, 18, 275301.	2.6	67
11	Electroâ€optic sampling of 1.5â€ps photoresponse signal from YBa2Cu3O7â^Î thin films. Applied Physics Letters, 1995, 67, 285-287.	3. 3	63
12	Phonon-wind-driven transport of photoexcited carriers in a semiconductor quantum well. Physical Review B, 1989, 39, 1862-1870.	3.2	58
13	Photovoltaic properties of M-phthalocyanine/fullerene organic solar cells. Solar Energy, 2012, 86, 1683-1688.	6.1	58
14	Origin of the fast photoresponse of epitaxialYBa2Cu3O7â^Îthin films. Physical Review B, 1993, 48, 16023-16039.	3.2	57
15	Subsurface modifications in indium phosphide induced by single and multiple femtosecond laser pulses: A study on the formation of periodic ripples. Journal of Applied Physics, 2007, 101, 033519.	2.5	55
16	Plasmon Field Effects on the Nonradiative Relaxation of Hot Electrons in an Electronically Quantized System: CdTeâ^'Au Coreâ^'Shell Nanowires. Nano Letters, 2008, 8, 2410-2418.	9.1	50
17	Ripple formation during deep hole drilling in copper with ultrashort laser pulses. Applied Physics A: Materials Science and Processing, 2007, 89, 1001-1003.	2.3	48
18	Ultrafast photoresponse in microbridges and pulse propagation in transmission lines made from high-T/sub c/ superconducting Y-Ba-Cu-O thin films. IEEE Journal of Selected Topics in Quantum Electronics, 1996, 2, 668-678.	2.9	47

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19	Strain relief and AlSb buffer layer morphology in GaSb heteroepitaxial films grown on Si as revealed by high-angle annular dark-field scanning transmission electron microscopy. Applied Physics Letters, 2011, 98, .	3.3	45
20	Pattern formation during laser melting of silicon. Physical Review B, 1989, 40, 3942-3954.	3.2	37
21	Infrared Hall Effect in High-TcSuperconductors: Evidence for Non-Fermi-Liquid Hall Scattering. Physical Review Letters, 2000, 84, 3418-3421.	7.8	35
22	Kinetics of plasmas and melting induced in silicon and germanium by nanosecond laser pulses. Physical Review B, 1984, 30, 1950-1956.	3.2	32
23	Current–voltage characteristics of dc voltage biased high temperature superconducting microbridges. Applied Physics Letters, 1995, 66, 2576-2578.	3.3	32
24	Bolometric technique for high-resolution broadband microwave spectroscopy of ultra-low-loss samples. Review of Scientific Instruments, 2004, 75, 124-135.	1.3	30
25	Order-Disorder Transitions in the Melt Morphology of Laser-Irradiated Silicon. Physical Review Letters, 1987, 58, 69-72.	7.8	29
26	The role of lattice mismatch in the deposition of CdTe thin films. Journal of Electronic Materials, 2006, 35, 1224-1230.	2.2	28
27	Femtosecond laser-based fabrication of a new model material to study fracture. Applied Physics A: Materials Science and Processing, 2006, 86, 55-61.	2.3	26
28	The role of substrate surface alteration in the fabrication of vertically aligned CdTe nanowires. Nanotechnology, 2008, 19, 185601.	2.6	26
29	Josephson current in an anisotropicd-wave model. Physical Review B, 1995, 51, 6588-6593.	3.2	25
30	Confinement of laserâ€generated carriers in semiconductors by induced lattice temperature gradients. Applied Physics Letters, 1982, 40, 385-387.	3.3	24
31	Time-resolved evolution of laser-induced periodic surface structure on germanium. Physical Review B, 1983, 27, 1424-1427.	3.2	24
32	Picosecond photoresponse of epitaxial YBa2Cu3O7â^'Î^ thin films. Applied Physics Letters, 1994, 64, 3172-3174.	3.3	24
33	Integration of an M-phthalocyanine layer into solution-processed organic photovoltaic cells for improved spectral coverage. Solar Energy Materials and Solar Cells, 2011, 95, 1970-1973.	6.2	24
34	Evaluation of LaSrGaO4 as a substrate for YBa2Cu3O7â ⁻ ¹Î´. Physica C: Superconductivity and Its Applications, 1994, 225, 7-12.	1.2	22
35	Magneto-optical Evidence for a Gapped Fermi Surface in UnderdopedYBa2Cu3O6+x. Physical Review Letters, 2004, 93, 137002.	7.8	22
36	Structural and transport properties of epitaxial niobium-doped BaTiO3 films. Applied Physics Letters, 2008, 93, 192114.	3.3	21

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37	Self-activated reversibility in the magnetically induced reorientation of martensitic variants in ferromagnetic Ni-Mn-Ga films. Physical Review B, 2010, 81, .	3.2	21
38	A simple parallel tandem organic solar cell based on metallophthalocyanines. Applied Physics Letters, 2011, 98, .	3.3	21
39	Epitaxially Driven Formation of Intricate Supported Gold Nanostructures on a Lattice-Matched Oxide Substrate. Nano Letters, 2009, 9, 4258-4263.	9.1	20
40	Insitugrowth of PbSrYCaCuO films by laser ablation. Applied Physics Letters, 1991, 58, 762-764.	3.3	18
41	Normal-state optical properties ofNd1.85Ce0.15CuO4+δ. Physical Review B, 1993, 47, 985-990.	3.2	17
42	Measurement of nonlinear absorption coefficients in GaAs, InP and Si by an optical pump THz probe technique. Optics Communications, 2007, 274, 187-197.	2.1	17
43	The Dependence of the Plasmon Field Induced Nonradiative Electronic Relaxation Mechanisms on the Gold Shell Thickness in Vertically Aligned CdTeâ^'Au Coreâ^'Shell Nanorods. Nano Letters, 2009, 9, 3772-3779.	9.1	17
44	Identification of nonbolometric photoresponse in YBa2Cu3O7â^δthin films based on magnetic field dependence. Applied Physics Letters, 1993, 62, 1158-1160.	3.3	16
45	Atypical grain growth for (211) CdTe films deposited on surface reconstructed (100) SrTiO3 substrates. Applied Surface Science, 2009, 255, 5674-5681.	6.1	16
46	Atomic structure and bonding of the interfacial bilayer between Au nanoparticles and epitaxially regrown MgAl2O4 substrates. Applied Physics Letters, 2014, 105, .	3.3	16
47	The role of substrate surface termination in the deposition ofÂ(111)ÂCdTe onÂ(0001) sapphire. Applied Physics A: Materials Science and Processing, 2009, 96, 429-433.	2.3	15
48	Exciton Lifetime Tuning by Changing the Plasmon Field Orientation with Respect to the Exciton Transition Moment Direction: CdTe-Au Coreâ 'Shell Nanorods. Nano Letters, 2009, 9, 1242-1248.	9.1	15
49	Interpretation of the harmonic response of superconducting films to inhomogeneous ac magnetic fields. Physical Review B, 1993, 48, 1077-1084.	3.2	14
50	Evolution of wurtzite CdTe through the formation of cluster assembled films. Applied Physics Letters, 2006, 89, 133101.	3.3	14
51	Plasmonic Enhancement of Nonradiative Charge Carrier Relaxation and Proposed Effects from Enhanced Radiative Electronic Processes in Semiconductorâ^'Gold Coreâ^'Shell Nanorod Arrays. Journal of Physical Chemistry C, 2011, 115, 5578-5583.	3.1	14
52	Rubrene as an additive in M-phthalocyanine/fullerene organic solar cells. Solar Energy Materials and Solar Cells, 2011, 95, 3137-3141.	6.2	13
53	Heteromorphic chloroindium phthalocyanine films for improved photovoltaic performance. Solar Energy Materials and Solar Cells, 2011, 95, 2937-2940.	6.2	13
54	Optical absorption in metallic-dielectric microstructures. Physical Review B, 1989, 40, 3931-3941.	3.2	10

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55	Growth of (Pb0.75Cu0.25)Sr2(Y1â^'yCay)Cu2O7thin films by laser ablation. Applied Physics Letters, 1991, 59, 2597-2599.	3.3	10
56	Laser ablation as a processing technique for metallic and polymer layered structures. IEEE Transactions on Semiconductor Manufacturing, 1994, 7, 73-78.	1.7	10
57	Growth of CdTeâ^•Si(100) thin films by pulsed laser deposition for photonic applications. Journal of Vacuum Science and Technology A: Vacuum, Surfaces and Films, 2006, 24, 606-611.	2.1	10
58	Blend composition study of poly(3,3‴-didodecylquaterthiophene)/[6,6]-phenyl C61 butyric acid methyl ester solution processed organic solar cells. Journal of Applied Physics, 2009, 105, 016105.	2.5	10
59	(100) MgAl2O4 as a lattice-matched substrate for the epitaxial thin film deposition of the relaxor ferroelectric PMN-PT. Applied Physics A: Materials Science and Processing, 2010, 98, 187-194.	2.3	9
60	Semiconductor nanotechnology: novel materials and devices for electronics, photonics and renewable energy applications. Nanotechnology, 2010, 21, 130201.	2.6	9
61	Evidence for an equilibrium epitaxial complexion at the Au-MgAl2O4 interface. Applied Physics Letters, 2015, 107, .	3.3	9
62	Quantum fluctuations in current-carrying thin films of YBa2Cu3O7â^Î. Physical Review B, 1997, 55, R14741-R14744.	3.2	8
63	Temperatureâ€Induced Atomic Reconstruction At Au/MgAl ₂ O ₄ Interfaces. Advanced Materials Interfaces, 2018, 5, 1701664.	3.7	8
64	Growth of Nd1.85Ce0.15CuO4+ $\hat{\Gamma}$ thin films by laser ablation. Physica C: Superconductivity and Its Applications, 1992, 197, 75-78.	1.2	7
65	Improved stability of solution processed photovoltaic devices using PQT-12. Solar Energy Materials and Solar Cells, 2010, 94, 2455-2458.	6.2	7
66	Switching speed for controlled damping using thin film YBa2Cu3O7-Î'. Cryogenics, 1997, 37, 113-116.	1.7	6
67	A DFT study on the effect of surface termination in CdTe (111)/ \hat{l} ±-Al2O3 (0001) heteroepitaxy. Surface Science, 2015, 632, 93-97.	1.9	6
68	A superconducting microwave switch. IEEE Transactions on Applied Superconductivity, 1995, 5, 3046-3048.	1.7	5
69	Observation of separate electron and hole escape rates in unbiased strained InGaAsP multiple quantum well laser structures. Applied Physics Letters, 1993, 62, 2525-2527.	3.3	4
70	Local characterization of Y-Ba-Cu-O thin films. IEEE Transactions on Applied Superconductivity, 2001, 11, 3226-3229.	1.7	4
71	Detwinning YBa2Cu3O7â~δ thin films. Applied Physics Letters, 2003, 82, 3728-3730.	3.3	4
72	Microstructure and current transport properties of single-layer YBa2Cu3O7â^'x and multiple-layer YBa2Cu3O7â^'x/(Ba0.05, Sr0.95)TiO3 superconductor films. Thin Solid Films, 2005, 488, 217-222.	1.8	4

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73	The origin of preferential twinning in YBa2Cu3O7â^î^thin films deposited on the (0 0 1) NdGaO3 substrate. Journal of Applied Physics, 2005, 97, 123906.	2.5	4
74	High-speed kinetic inductive bolometric photoresponse of epitaxial YBa 2 Cu 3 O 7- $\hat{\Gamma}$ thin films. , 1994, 2159, 88.		3
75	Defect characterization of CdTe thin films using a slow positron beam. Physica Status Solidi C: Current Topics in Solid State Physics, 2007, 4, 3659-3663.	0.8	3
76	Percolative effects in oxygen-depletedYBa2Cu3Oxwires. Physical Review B, 2004, 70, .	3.2	2
77	Chemically ordered fcc (111) Mn–(FexNi1â^'x) alloy ultrathin films. Surface Science, 2005, 588, 49-60.	1.9	2
78	$$ $$ $$ $$ $$ $$ $$ $$ $$		1
79	Picosecond photoresponse of YBa2Cu3O7â°'x thin films. European Physical Journal D, 1996, 46, 1111-1112.	0.4	1
80	The role of lattice misfit strains in the deposition of epitaxial (Ba1â^'ySry)Ti0.5Nb0.5O3 films. Journal of Crystal Growth, 2009, 311, 2753-2758.	1.5	1
81	Purified water etching of native oxides on heteroepitaxial CdTe thin films. Journal Physics D: Applied Physics, 2014, 47, 495304.	2.8	1
82	Spontaneous Relaxation of Heteroepitaxial Thin Films by van der Waalsâ€Like Bonding on Teâ€Terminated Sapphire Substrates. Small, 2020, 16, e2004437.	10.0	1
83	Observation of a soret-dufour effect for laser-generated carriers in germanium. Physica B: Physics of Condensed Matter & C: Atomic, Molecular and Plasma Physics, Optics, 1983, 117-118, 1021-1023.	0.9	0
84	Flux dynamics in thin films of YBa2Cu3O7â^î. European Physical Journal D, 1996, 46, 1633-1634.	0.4	0
85	Penetration depth from far-infrared transmission in YBa2Cu3O7 thin films. Nuovo Cimento Della Societa Italiana Di Fisica D - Condensed Matter, Atomic, Molecular and Chemical Physics, Biophysics, 1998, 20, 563-572.	0.4	0
86	Terahertz pump-probe spectroscopy in YBCO thin films. , 2004, , .		0
87	Laser Scanning Microscopy Studies on Detwinned <tex>\$rm YBa_2rm Cu_3rm O_7-delta\$</tex> Thin Films. IEEE Transactions on Applied Superconductivity, 2005, 15, 3082-3085.	1.7	0
88	The rapid prototyping of textured amorphous surfaces forÂtheÂgraphoepitaxial deposition of CdTe films usingÂfocusedÂionÂbeamÂlithography. Applied Physics A: Materials Science and Processing, 2011, 102, 259-264.	2.3	0
89	Metal-Oxide Interfaces: Temperature-Induced Atomic Reconstruction At Au/MgAl2 O4 Interfaces (Adv.) Tj ETQq1	1 0.7843	14 rgBT /Over